Diode Semiconductor Device - Page 1 of 1



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## Inclosure Material:

Metal

**Overall Length:** 

1.250 inches

# Mounting Facility Quantity:

1

#### Joint Electronic Device Engineering Council/jedec/case Outline Designation:

D0-4

## Mounting Method:

Threaded stud

## Features Provided:

Electrostatic sensitive and hermetically sealed case

# **Overall Width Across Flats:**

Between 0.429 inches and 0.434 inches

# Thread Size:

# 0.190 inches

# Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

500.0 reverse voltage, instantaneous

## **Current Rating Per Characteristic:**

15.00 amperes forward current, average

#### Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

#### **Thread Series Designator:**

Unf

#### **Terminal Type And Quantity:**

1 tab, solder lug and 1 threaded stud

#### Shelf Life:

N/a

#### Unit Of Measure:

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## Demilitarization:

No

#### Fiig:

A110a0